



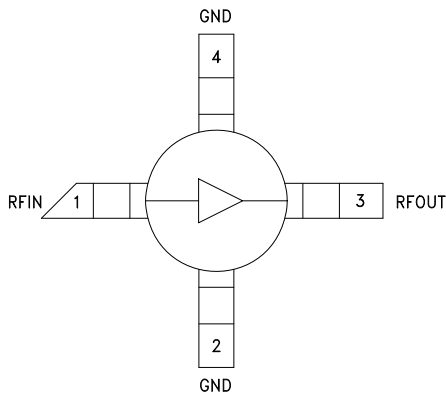
SiGe HBT GAIN BLOCK MMIC AMPLIFIER, DC - 5 GHz

Typical Applications

The HMC479MP86 / HMC479MP86E is an ideal RF/IF gain block & LO or PA driver:

- Cellular / PCS / 3G
- Fixed Wireless & WLAN
- CATV, Cable Modem & DBS
- Microwave Radio & Test Equipment

Functional Diagram



Features

- P1dB Output Power: +18 dBm
- Gain: 15 dB
- Output IP3: +34 dBm
- Cascadable 50 Ohm I/Os
- Single Supply: +5V to +12V
- Included in the HMC-DK001 Designer's Kit

General Description

The HMC479MP86 & HMC479MP86E are SiGe Heterojunction Bipolar Transistor (HBT) Gain Block MMIC SMT amplifiers covering DC to 5 GHz. This Micro-P packaged amplifier can be used as a cascadable 50 Ohm RF/IF gain stage as well as a LO or PA driver with up to +21 dBm output power. The HMC479MP86(E) offers 15 dB of gain with a +34 dBm output IP3 at 850 MHz while requiring only 72 mA from a single positive supply. The Darlington feedback pair used results in reduced sensitivity to normal process variations and excellent gain stability over temperature while requiring a minimal number of external bias components.

Electrical Specifications, $V_s = 8.0\text{ V}$, $R_{bias} = 51\text{ Ohm}$, $T_A = +25^\circ\text{ C}$

Parameter		Min.	Typ.	Max.	Units
Gain	DC - 1.0 GHz	12.5	14.5		dB
	1.0 - 2.0 GHz	11.5	13		dB
	2.0 - 3.0 GHz	10.5	12		dB
	3.0 - 4.0 GHz	9	11		dB
	4.0 - 5.0 GHz	7.5	9.5		dB
Gain Variation Over Temperature	DC - 5 GHz		0.008	0.012	dB/ °C
Input Return Loss	DC - 1.0 GHz		12		dB
	1.0 - 2.0 GHz		16		dB
	2.0 - 4.0 GHz		18		dB
	4.0 - 5.0 GHz		15		dB
Output Return Loss	DC - 1.0 GHz		18		dB
	1.0 - 3.5 GHz		25		dB
	3.5 - 5.0 GHz		15		dB
Reverse Isolation	DC - 5 GHz		18		dB
Output Power for 1 dB Compression (P1dB)	0.5 - 1.0 GHz	16	18.5		dBm
	1.0 - 2.5 GHz	13	17		dBm
	2.5 - 4.0 GHz	11	14		dBm
	4.0 - 5.0 GHz	9	12		dBm
Output Third Order Intercept (IP3) (Pout= 0 dBm per tone, 1 MHz spacing)	0.5 - 1.0 GHz		34		dBm
	1.0 - 2.5 GHz		32		dBm
	2.5 - 4.0 GHz		28		dBm
	4.0 - 5.0 GHz		25		dBm
Noise Figure	DC - 2.0 GHz		4.0		dB
	2.0 - 5.0 GHz		4.8		dB
Supply Current (Icq)			72	100	mA

Note: Data taken with broadband bias tee on device output.

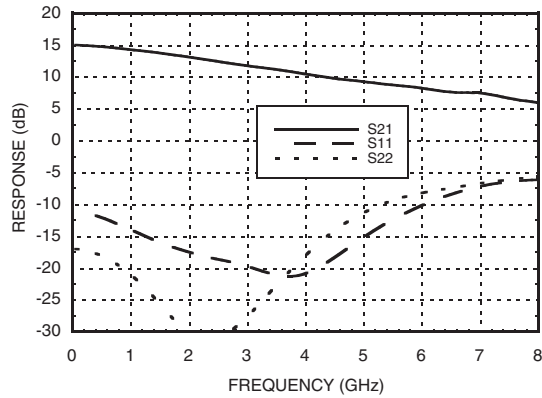
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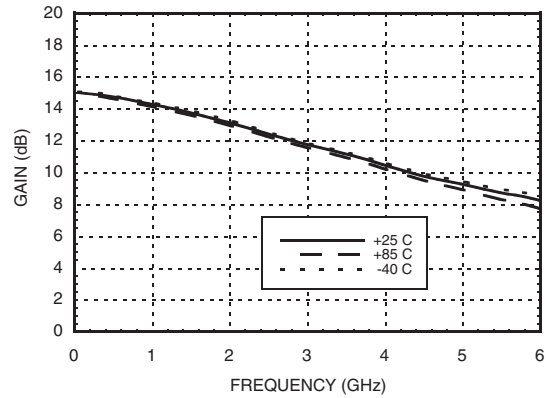


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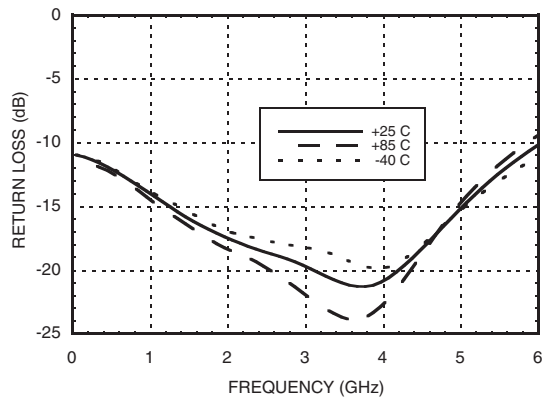
Broadband Gain & Return Loss



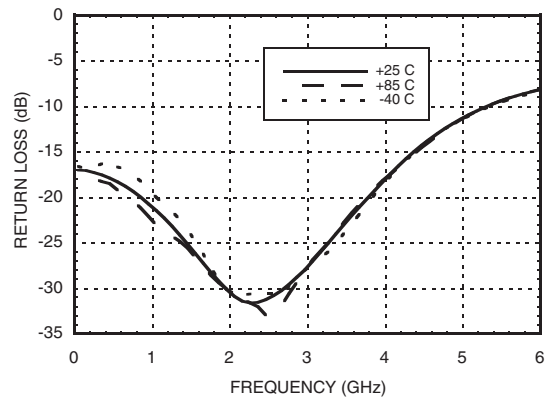
Gain vs. Temperature



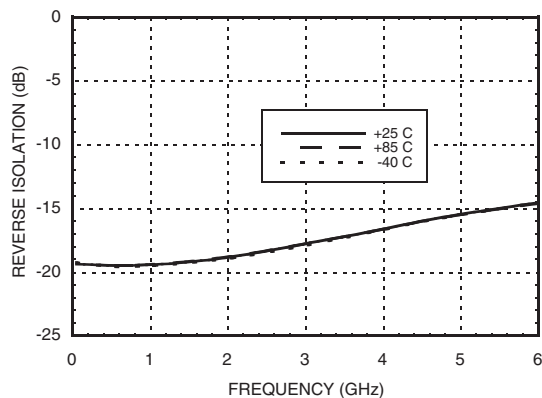
Input Return Loss vs. Temperature



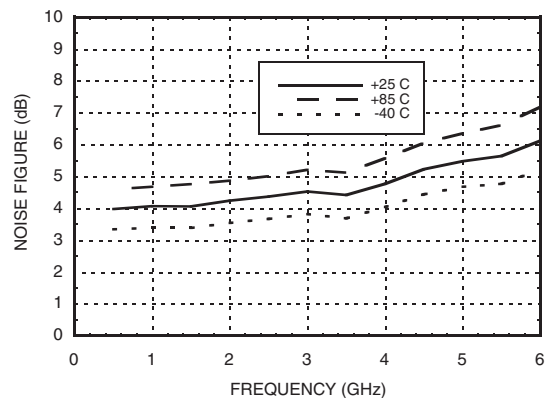
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature



Noise Figure vs. Temperature



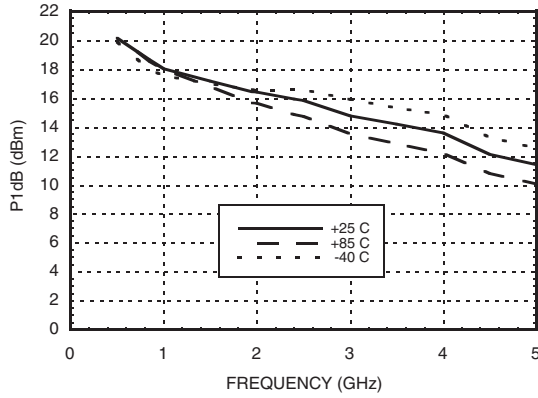
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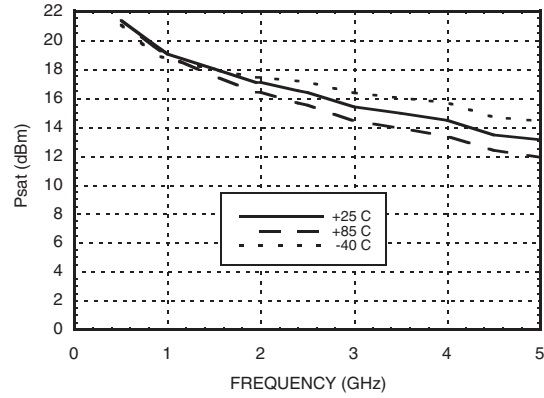


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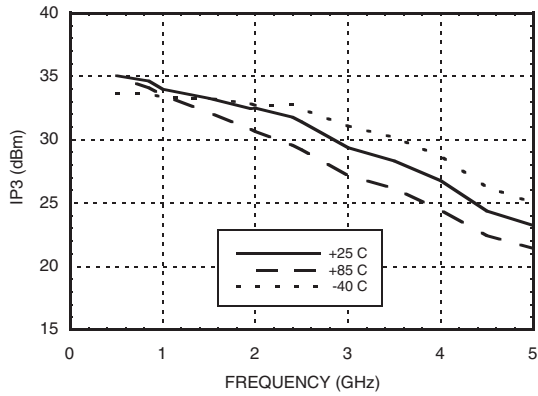
P1dB vs. Temperature



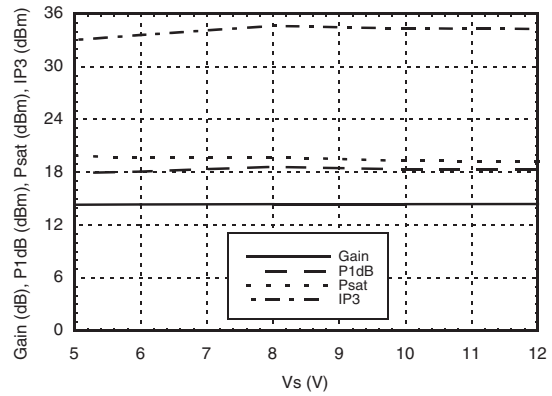
Psat vs. Temperature



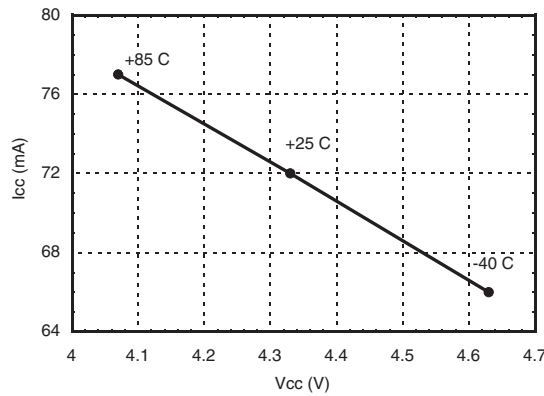
Output IP3 vs. Temperature



**Gain, Power & OIP3 vs. Supply Voltage
for Constant Icc= 72 mA @ 850 MHz**



**Vcc vs. Icc Over Temperature for
Fixed Vs= 8V, RBIAS= 51 Ohms**



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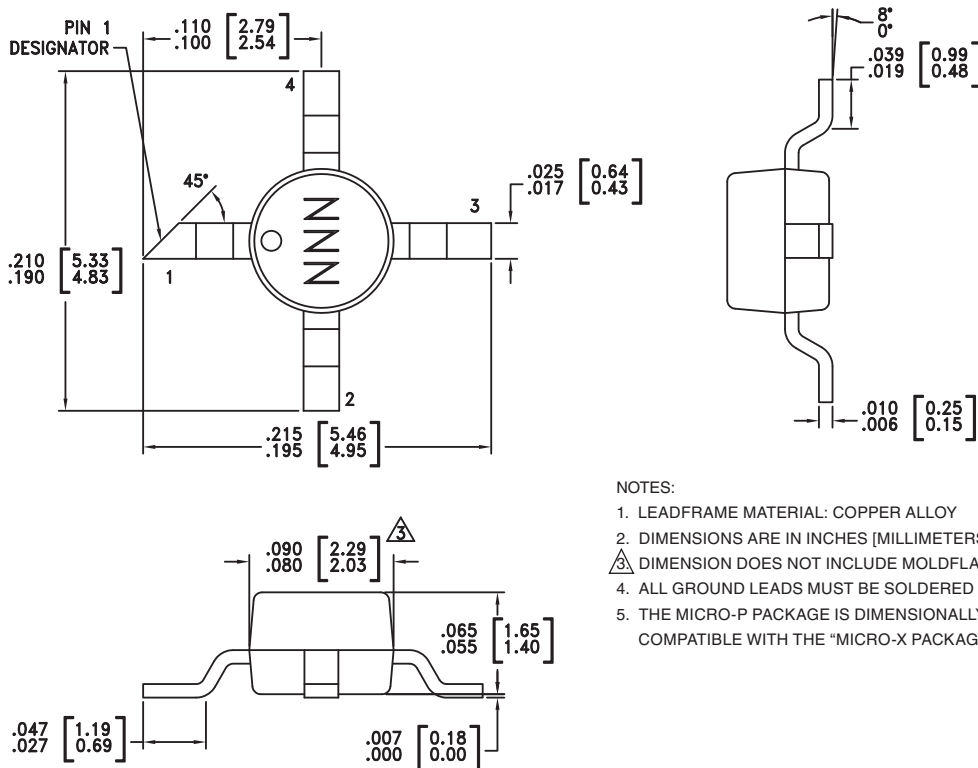
Absolute Maximum Ratings

Collector Bias Voltage (Vcc)	+6 Vdc
Collector Bias Current (Icc)	100 mA
RF Input Power (RFIN)(Vcc = +4.3 Vdc)	+17 dBm
Junction Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 10.8 mW/°C above 85 °C)	0.702 W
Thermal Resistance (junction to lead)	92.6 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



NOTES:

1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
4. ALL GROUND LEADS MUST BE SOLDERED TO PCB RF GROUND.
5. THE MICRO-P PACKAGE IS DIMENSIONALLY COMPATIBLE WITH THE "MICRO-X PACKAGE"

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking
HMC479MP86	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	479
HMC479MP86E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	<u>479</u>

[1] Max peak reflow temperature of 235 °C

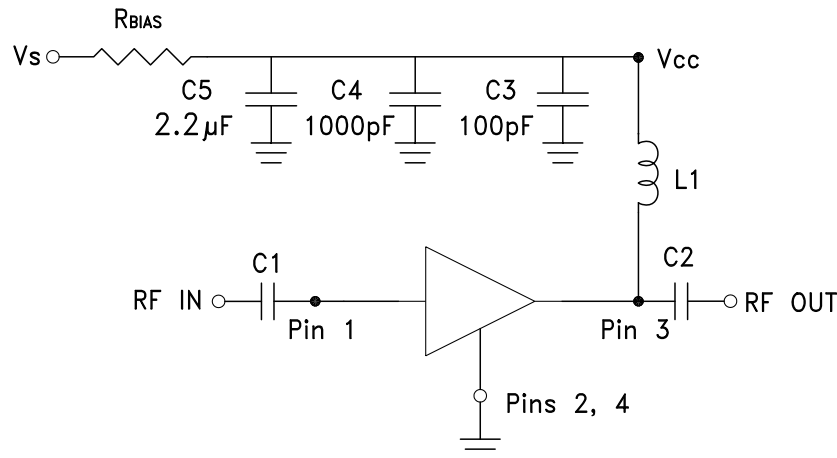
[2] Max peak reflow temperature of 260 °C



Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFIN	This pin is DC coupled. An off chip DC blocking capacitor is required.	
3	RFOUT	RF output and DC Bias (Vcc) for the output stage.	
2, 4	GND	These pins must be connected to RF/DC ground.	

Application Circuit



Recommended Bias Resistor Values for $I_{cc} = 72 \text{ mA}$, $R_{BIAS} = (V_s - V_{cc}) / I_{cc}$

Supply Voltage (Vs)	5V	6V	8V	10V	12V
RBIAS VALUE	13 Ω	27 Ω	51 Ω	82 Ω	110 Ω
RBIAS POWER RATING	1/8 W	1/4 W	1/2 W	1/2 W	1 W

Note:

- External blocking capacitors are required on RFIN and RFOUT.
- RBIAS provides DC bias stability over temperature.

Recommended Component Values for Key Application Frequencies

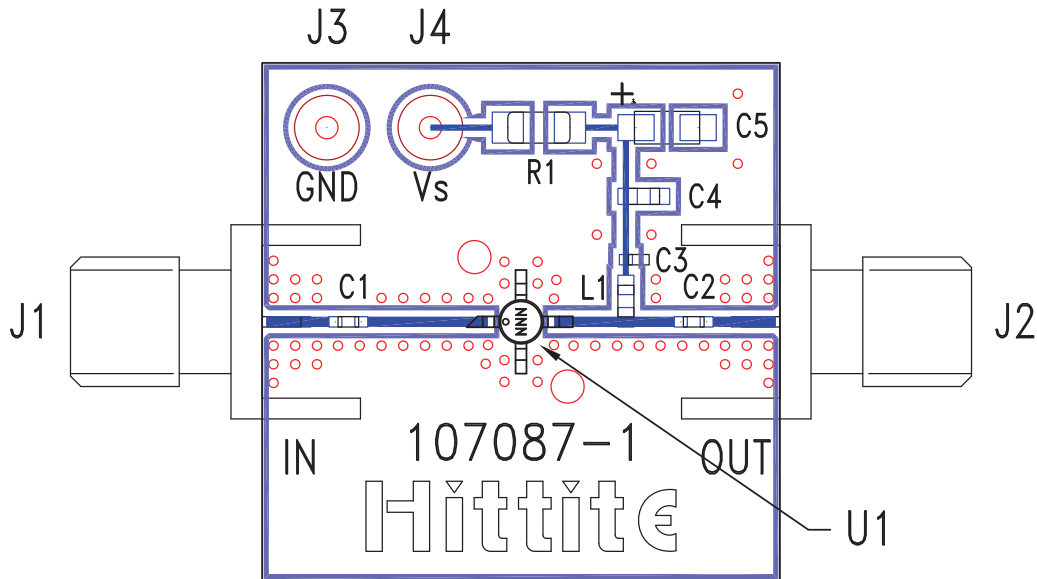
Component	Frequency (MHz)						
	50	900	1900	2200	2400	3500	5000
L1	270 nH	56 nH	18 nH	18 nH	15 nH	8.2 nH	6.8 nH
C1, C2	0.01 μF	100 pF	100 pF	100 pF	100 pF	100 pF	100 pF

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Evaluation PCB



List of Materials for Evaluation PCB 107489 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3 - J4	DC Pin
C1, C2	Capacitor, 0402 Pkg.
C3	100 pF Capacitor, 0402 Pkg.
C4	1000 pF Capacitor, 0603 Pkg.
C5	2.2 μ F Capacitor, Tantalum
R1	Resistor, 1210 Pkg.
L1	Inductor, 0603 Pkg.
U1	HMC479MP86 / HMC479MP86E
PCB [2]	107087 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.